

IN THE U.S. PATENT AND TRADEMARK OFFICE

Applicant(s): GIL, Gyoung-Seon

Application No.:

Filed: August 25, 1998

For: THIN FILM TRANSISTOR AND FABRICATION METHOD THEREFOR

COPY

Group:

Examiner:

JC913 U.S. PRO
09/689746
10/13/00

L E T T E R

Assistant Commissioner for Patents
Box Patent Application
Washington, D.C. 20231

August 25, 1998
0630-0842P

Sir:

Under the provisions of 35 USC 119 and 37 CFR 1.55(a), the applicant hereby claims the right of priority based on the following application(s):

<u>Country</u>	<u>Application No.</u>	<u>Filed</u>
REPUBLIC OF KOREA	97-70069	12/17/97

A certified copy of the above-noted application(s) is(are) attached hereto.

If necessary, the Commissioner is hereby authorized in this, concurrent, and future replies, to charge payment or credit any overpayment to deposit Account No. 02-2448 for any additional fees required under 37 C.F.R. 1.16 or under 37 C.F.R. 1.17; particularly, extension of time fees.

Respectfully submitted,

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Priority Gyoung-Seon Gi
Paper 630-842P
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대한민국 특허청
KOREAN INDUSTRIAL
PROPERTY OFFICE

별첨 사본은 아래 출원의 원본과 동일함을 증명함.

This is to certify that the following application annexed hereto
is a true copy from the records of the Korean Industrial
Property Office.

출원번호 : 1997년 특허출원 제70069호
Application Number

출원년월일 : 1997년 12월 17일
Date of Application

출원인 : 엘지반도체주식회사
Applicant(s)

1998년 1월 14일

특허청

COMMISSIONER

